THE DATASHEET OF

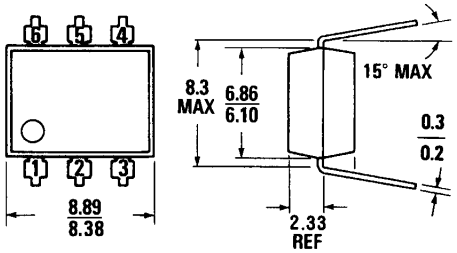
H11N3

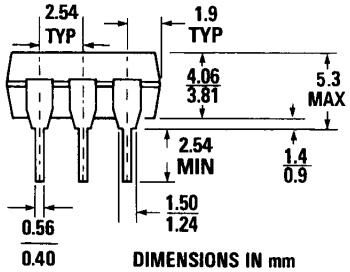
FAIRCHILD
SEMICONDUCTOR™

HIGH-SPEED AlGaAS SCHMITT TRIGGER OPTOCOUPLERS

H11N1 H11N2 H11N3

PACKAGE DIMENSIONS





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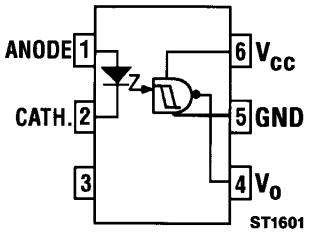
ST1603A



Equivalent Circuit

DESCRIPTION

The H11N series has a medium-to-high speed integrated circuit detector optically coupled to a gallium-aluminum-arsenide infrared emitting diode. The output incorporates a Schmitt trigger, which provides hysteresis for noise immunity and pulse shaping. The detector circuit is optimized for simplicity of operation and utilizes an open collector output for maximum application flexibility.

FEATURES & APPLICATIONS

- High data rate, 5 MHz typical (NRZ)
- Free from latch up and oscillation throughout voltage and temperature ranges
- Microprocessor compatible drive
- Logic compatible output sinks 16 mA at 0.5 V maximum
- Guaranteed on/off threshold hysteresis
- High common mode transient immunity 2000 V/μs minimum
- Fast switching: t_r, t_f=10 ns typical
- Wide supply voltage capability, compatible with all popular logic systems
- Underwriters Laboratory (UL) recognized — file #E90700
- Logic to logic isolator
- Programmable current level sensor
- Line receiver—eliminates noise and transient problems
- Logic level shifter—couples TTL to CMOS
- A.C. to TTL conversion—square wave shaping
- Isolated power MOS driver for power supplies
- Interfaces computers with peripherals

ABSOLUTE MAXIMUM RATINGS

TOTAL PACKAGE

Storage temperature ..... −55°C to 125°C
Operating temperature ..... −25°C to 85°C
Lead solder temperature ..... 260°C for 10 sec

INPUT DIODE

Power dissipation (25°C ambient) ..... 50 mW
Derate linearly (above 70°C) ..... 1.67 mW/°C
Continuous forward current ..... 30 mA
Peak forward current
(300μs pulse, 2% duty cycle) ..... 50 mA
Reverse voltage ..... 6 V

DETECTOR

Power dissipation (at 25°C ambient) ..... 150 mW
Derate linearly (above 25°C ambient) ..... 5 mW/°C
V_{45} allowed range ..... 0 to 16 V
V_{65} allowed range ..... 0 to 16 V
I_4 output current ..... 50 mA

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ELECTRICAL CHARACTERISTICS (T_A= 0-70°C Unless Otherwise Specified) Note 1

INDIVIDUAL COMPONENT CHARACTERISTICS

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
INPUT DIODE						
Forward voltage	V_F		1.6	2.0	V	I_F=10 mA
	V_F	0.75	1.45		V	I_F=0.3 mA
Reverse current	I_R			10	μA	V_R=5 V, T_A=25°C
	I_R			100	μA	V_R=5 V, T_A=100°C
Capacitance	C_J			100	pF	V=0 V, f=1 MHz
OUTPUT DETECTOR						
Operating voltage range	V_{CC}	4		15	V	
Supply current	$I_{6(off)}$		5.5	10	mA	I_F=0, V_{CC}=5 V
Output current, high	I_{OH}			100	μA	I_F=0.3 mA, V_{CC}=V_O=15 V

TRANSFER CHARACTERISTICS (T_A = 0-70°C) Note 1

CHARACTERISTIC		SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
Supply current		$I_{6(on)}$		5	10	mA	I_F=10 mA, V_{CC}=5 V
Output voltage, low		V_{OL}		0.3	0.5	V	R_L=270 Ω, V_{CC}=5 V, I_F=$I_{F(on)}$ max.
Turn-on threshold current	(H11N1)	$I_{F(on)}$	0.8		3.2	mA	R_L=270 Ω, V_{CC}=5 V
	(H11N2)	$I_{F(on)}$	2.3		5.0	mA	R_L=270 Ω, V_{CC}=5 V
	(H11N3)	$I_{F(on)}$	4.1		10.0	mA	R_L=270 Ω, V_{CC}=5 V
Turn-off threshold current		$I_{F(off)}$	0.3	1.5		mA	R_L=270 Ω, V_{CC}=5 V
Hysteresis ratio		$I_{F(off)}/I_{F(on)}$	0.65	0.8	0.95		R_L=270 Ω, V_{CC}=5 V

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DYNAMIC CHARACTERISTICS (T_A = 0-70°C) Note 1

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
SWITCHING SPEED (Figures 7&8)						
Propagation delay, high to low	t_{PHL}		150	330	ns	C=120 pF, t_p=1 μs, R_E: Note 4
Rise time	t_r		10		ns	C=120 pF, t_p=1 μs, R_E: Note 4
Propagation delay, low to high	t_{PLH}		150	330	ns	C=120 pF, t_p=1 μs, R_E: Note 4
Fall time	t_f		15		ns	C=120 pF, t_p=1 μs, R_E: Note 4
Data rate			5		MHz	Note 3
OVERDRIVE SWITCHING (FIGURES 7&8), NOTE 2						
Turn-off time	t_{off}		0.2	0.5	μs	C=O, R_L=270 Ω, I_F(MAX) H11N1: 5 mA H11N2: 10 mA H11N3: 20 mA
TRANSIENT IMMUNITY (FIGURE 9)						
Common mode transient immunity	CM_H	±2000	±10000		V/μs	V_{pk}=50 V, V_{CC}=5 V, R_L=270 Ω, I_F=0
Common mode transient immunity	CM_L	±2000	±10000		V/μs	V_{pk}=50 V, V_{CC}=5 V, R_L=270 Ω, I_F=0

ISOLATION CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
Surge isolation voltage	V_{ISO}	7500			V_{PEAK}	1 Minute
Surge isolation voltage	V_{ISO}	5300			V_{RMS}	1 Minute

Notes

1. *All measurements are with 100nF bypass capacitor from pin 6 to pin 5.*
2. *Steady overdrive increases t_{off}. Use of a large R_F and a small C as in figure 7 is preferred over overdrive current.*
3. *Maximum data rate will vary depending on the bias conditions and is usually highest when R_E and C are matched to $I_{F(ON)}$ and V_{CC} is between 5 and 15V. With this optimized bias, most units will operate at over 10 MHz, NRZ.*
4. *H11N1: R_E = 910Ω, H11N2: R_E = 560Ω, H11N3: R_E = 240Ω.*

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OPTOISOLATOR SPECIFICATIONS

TYPICAL CHARACTERISTICS

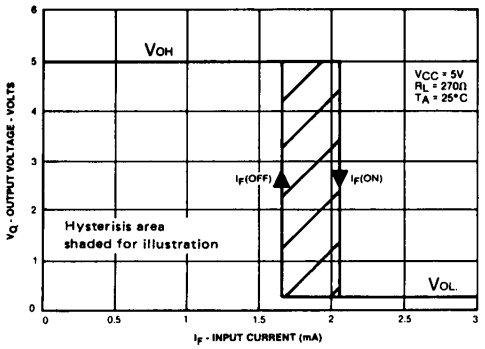


Figure 1. Transfer characteristics ST2022

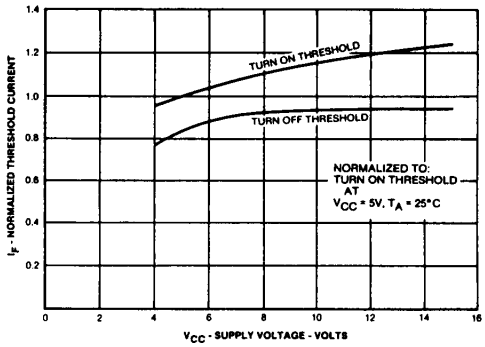


Figure 2. Threshold current vs. supply voltage ST2023

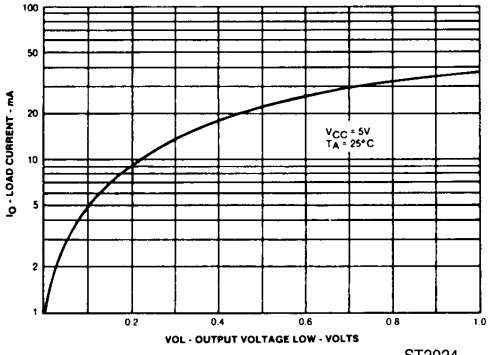


Figure 3. ON voltage vs. current ST2024

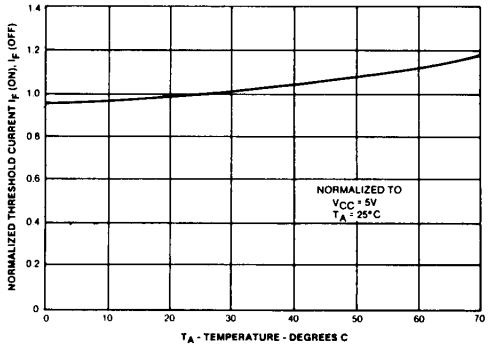


Figure 4. Threshold current vs. temperature ST2025

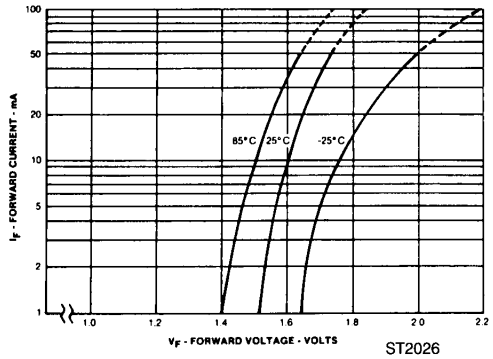


Figure 5. Forward voltage vs. forward current ST2026

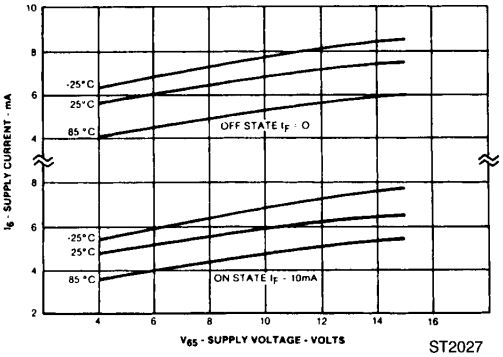
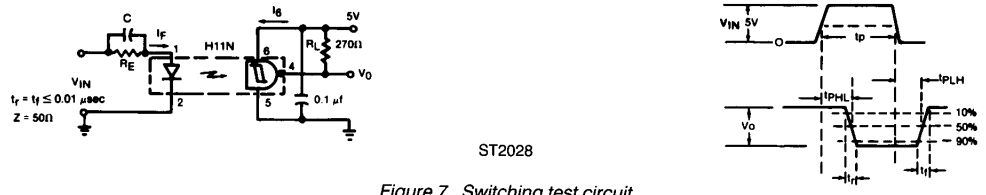


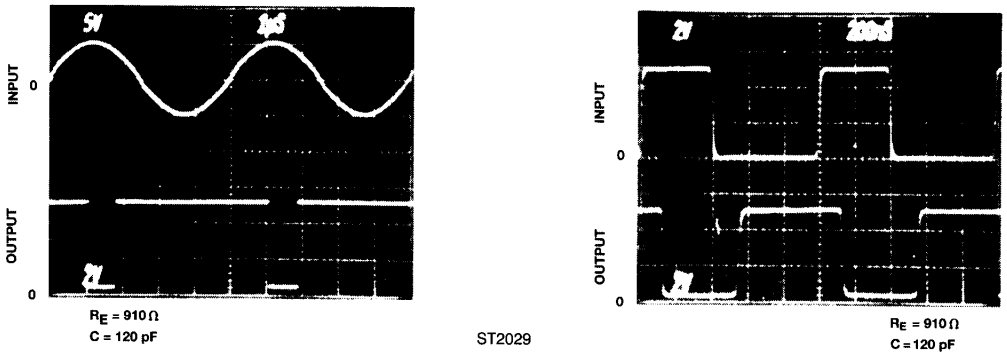
Figure 6. Supply current vs. supply voltage ST2027

TYPICAL CHARACTERISTICS



ST2028

Figure 7. Switching test circuit

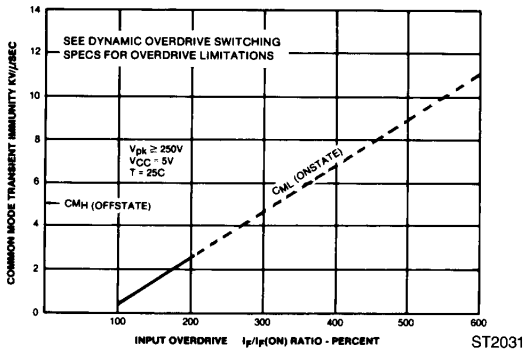


ST2029

Figure 8. Switching test waveforms

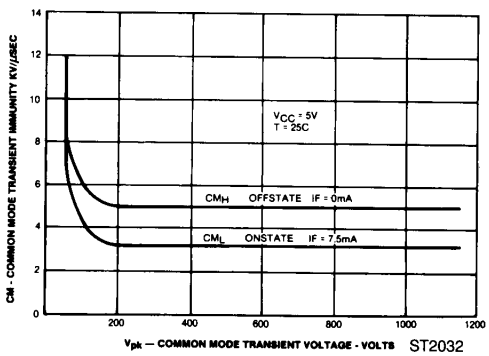
ST2030

Figure 9. Common-mode transient immunity, test circuit and voltage waveforms



ST2031

Figure 10. CM_L and CM_H input current



ST2032

Figure 11. CM_L and CM_H vs. common-mode transient voltage

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